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(996303) (lining liner sidewall side adj wall)
(215115) 21.clm.
(22) (17.clm. near3 2.clm.) with 21.clm.
(5) ((17.clm. near3 2.clm.) with 21.clm.) and ((ferr?electric ferr? adj electric ferr?mag
(17) (17.clm. near3 2.clm.) with 21.clm.) not ((17.clm. near3 2.clm.) with 21.clm.) and
(2) 8485989.pn.
(6888170) after before follow\$4
(1561520) capacit\$4
(6838) ((open\$5 via plug hole)) near9 (after before follow\$4) near9 capacit\$4
(54) (((fet field adj effect adj transistor))
(26361950) (@pd @ad) < "20001117"
(464) 28.clm.
(8) (((fet field adj effect adj transistor))
(35) (((fet field adj effect adj transistor))
(13) (((fet field adj effect adj transistor))
(6) 8174786.URFN
(10) ("5100826" | "5439840" | "5510654" | "5681425" | "5783482" | "584118
(686) (((fet field adj effect adj transistor))
(4) ((ferr?electric ferr? adj electric ferr?magnetic ferr? adj magnetic FeRam FRAM)
(38) (((fet field adj effect adj transistor))
(247316) (lower bottom) adj2 (plate electrode)
(27) (((fet field adj effect adj transistor))

-  Favorites
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-  Queue

<input type="button" value="New"/>	<input type="button" value="Save"/>	<input type="button" value="Browse"/>	<input type="button" value="Query"/>	<input type="button" value="Clear"/>
<input type="text" value="QDs"/>	<input type="text" value="USPAT:US PGPUB; EPO:JPO; DERIVENT; IDM_TDB"/>			<input type="button" value="P Plurals"/>
Default operator:	<input type="text" value="OR"/>			<input type="button" value="P Highlight all hit terms initially"/>

(((fer field adj effect adj transistor)
 (\$(\$mos metal adj oxide) adj transistor) mosfet)
) same (((nonvolatile non adj volatile) adj memory flash EEPROM aPROM nVMe nOVRam)) and (((open\$5 via plug hole)) near9 (after
 before follow\$4) near9 capacit\$4) and ((@p @ad < "20001117") (((fer?electric fer? adj electric fer?magnetic fer? adj
 magnetic FeRam FRAM): (magnetic adj memory mram) (magnetoresist\$4 magneto adj resist\$4): (magnetoresist\$4 magneto adj
 resist\$4 TMR) (mtj magnetic adj tunnel adj junction)) and ("5100826" | "5439840" | "5510654" | "5681425" | "5783482"
 "5841160" | "5828475" | "5981333" | "5885713" | "6057205".PN)

May 2004

	#	1	inventor	Document#	Issue	Pages	Title	Current	Current	XR	Retrieval	S	C	P	S	S	Image	Doc	P
1			Hayashi, Yos	US 6174766	20010:43		Semiconductor device and method of manufa	438/241	257/E21.00								US 6174766		
2			Jones, Jr., Ro	US 5439840	19950:16		Method of forming a nonvolatile random acc	438/3	257/E27.08								US 5439840		
3			Asada, Hiroo	US 6659352	20031:26		Semiconductor integrated circuit, a contact	235/482	235/487								US 6659352		
4			Choi, Kyu Hy	US 6514819	20030:23		High capacity stacked DRAM device and pro	438/253	257/E21.64								US 6514819		
5			Guej, Marc	US 6404679	20020:12		Multiple level floating-gate memory	365/185	365/185.03								US 6404679		
6			Torii, Kazuyo	US 6390574	20020:29		Ferroelectric capacitor with a self-aligned di	257/295	257/310								US 6390574		
7			Shau, Jeng-J	US 6377484	20020:17		Embedded electrically programmable read o	365/185	365/145								US 6377484		
8			Nagamine, M	US 6287988	20010:58		Semiconductor device manufacturing metho	438/770	257/E21.19								US 6287988		
9			Maymood, Y	US 6206282	20010:76		A/D converter with input capacitor, feedback	341/158	341/172								US 6206282		
10			Caywood, Jo	US 6201732	20010:40		Low voltage single CMOS electrically erasab	365/185	257/E27.10								US 6201732		